MAPS Simulation Status

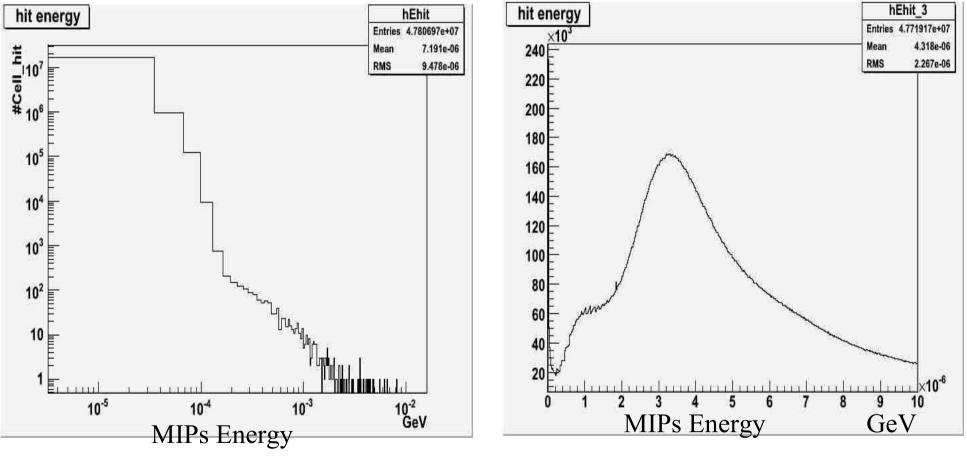
5th October 2006 MAPS meeting at Rutherford Appleton Laboratory <u>Yoshinari Mikami</u> University of Birmingham

Contents

Energy deposit distribution
48 contiguous cells hits pattern

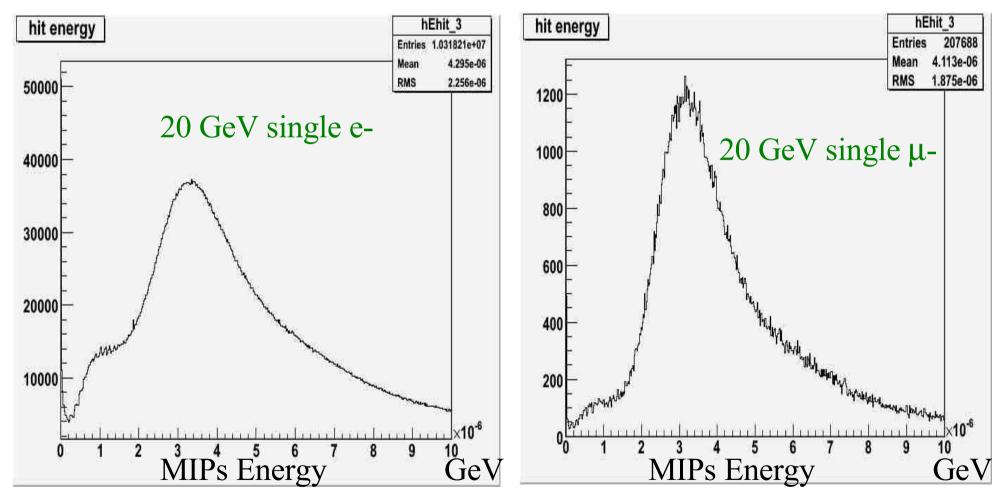
- -15µm Si sensitive thickness
- -50µm x 50µm cell size

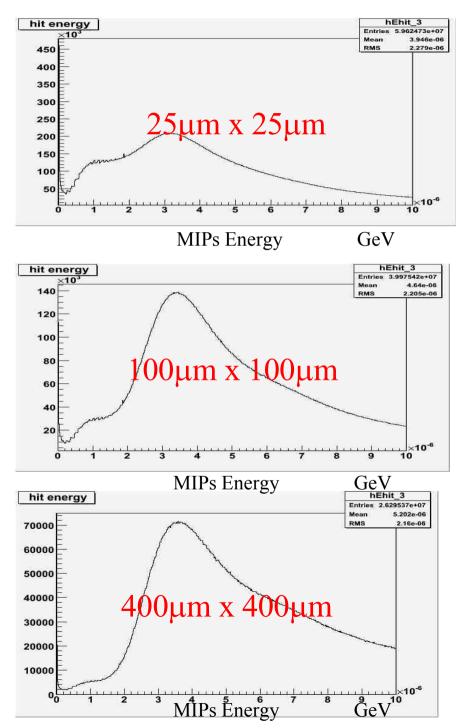
-100 GeV single electron



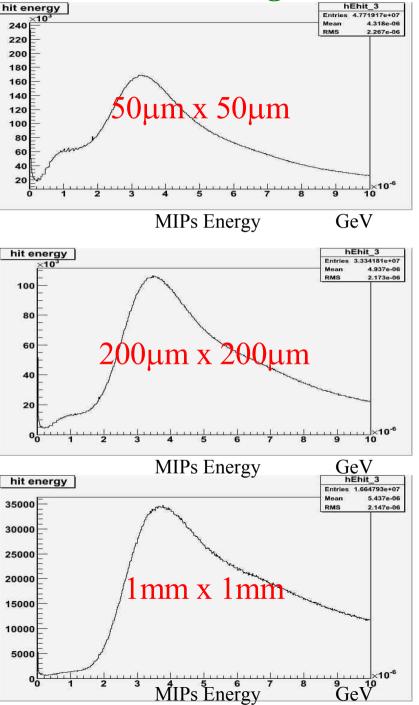
~3.5 KeV MIPs peak

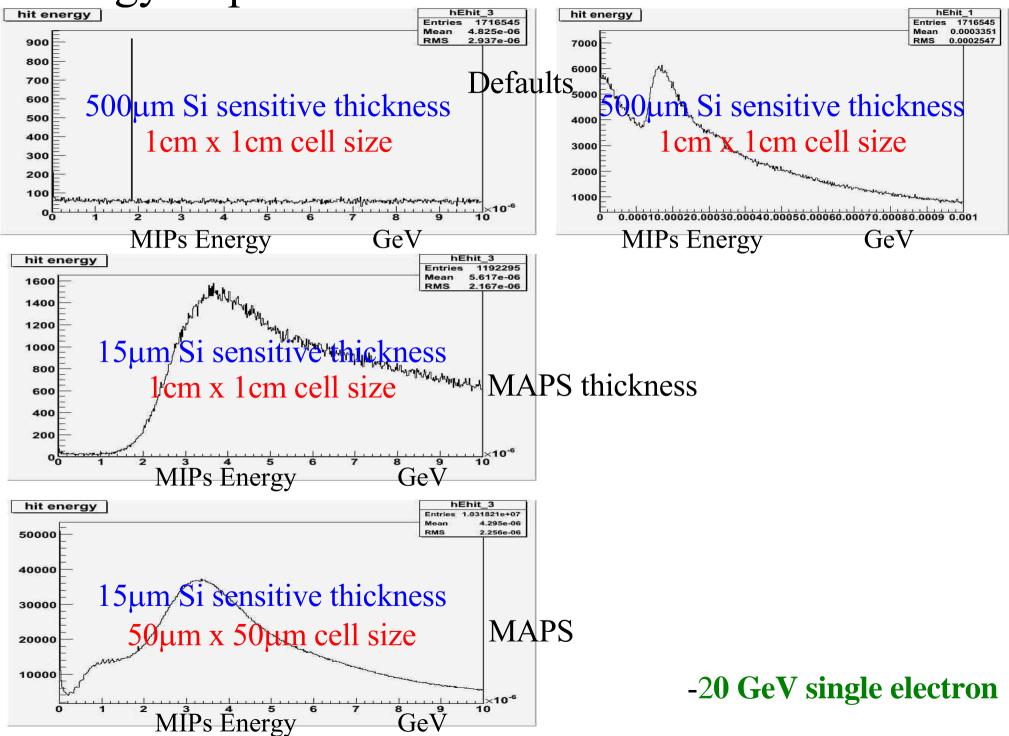
- -15µm Si sensitive thickness
- -50µm x 50µm cell size



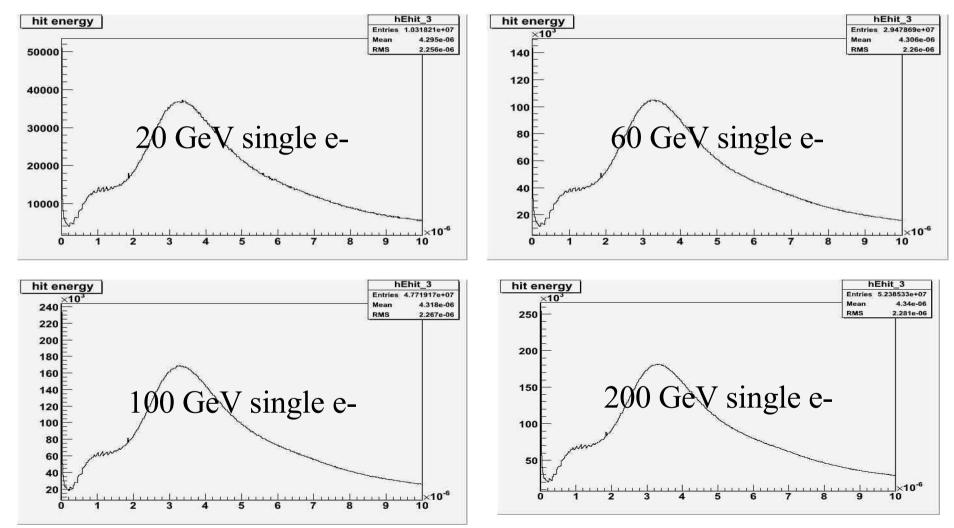


-15µm Si sensitive thickness -100 GeV single electron





- $-15\mu m$ Si sensitive thickness
- -50µm x 50µm cell size



Mean value dose not depend on incoming electron energies. --->Single MIP in each cell. (Individual MIP can be detected.)

48 contiguous cell hit pattern study (Under study)

CellID0 -Stave CellID1 -Cell z index -Module -Provision -Layer -sign -Cell x index -Guard-ring zone -Sign

After extracting Cell z index from CellID1, contiguous 48 hits are added with requiring the same CellID0.

- (Double counts are removed.)
 - →Code is almost available.

Hopefully, I can show some distributions in next meeting.

Summary of status

-48 contiguous cell hit pattern is probably available in the next.

 -Individual secondary particle angle study depends on getNMCcontributions() output.
 <-- I have to ask some expart about this.

-50um x 50um pixel size seems to be optimized.